

Product Summary

BV _{DSS}	Rds(on) Max	I _D Max T _A = +25°C	
<u>cov</u> /	65mΩ @ V _{GS} = 10V	3.8A	
60V	88mΩ @ VGS = 4.5V	3.3A	

Description and Applications

This MOSFET has been designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Backlighting
- Power Management Functions
- DC-DC Converters

Features and Benefits

- Rated to +175°C– Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotiveproducts/.

- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.
- https://www.diodes.com/quality/product-definitions/ An Automotive-Compliant Part is Available Under Separate
- Datasheet (<u>DMNH6065SSDQ</u>)

Mechanical Data

- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram

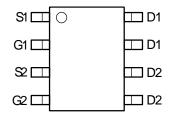
D1

• Terminals: Finish — Matte Tin Annealed over Copper Leadframe Solderable per MIL-STD-202, Method 208 (3)

D2

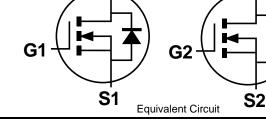
• Weight: 0.074 grams (Approximate)





Top View

Pin Configuration



Top View Ordering Information (Note 4)

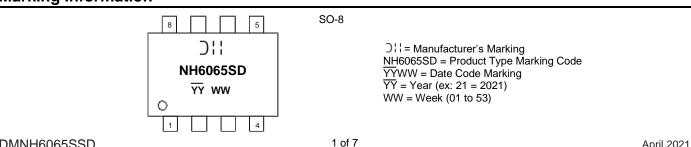
Part Number	Case	Packaging
DMNH6065SSD-13	SO-8	2,500/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information





Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			Vdss	60	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current (Note 6) V _{GS} = 10V	Steady State	T _A = +25°C T _A = +100°C	ID	3.8 2.7	А
Maximum Continuous Body Diode Forward Current (Note 6)			ls	3.8	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			ldм	30	А
Avalanche Current, L = 1mH			las	13	А
Avalanche Energy, L = 1mH			Eas	84.5	mJ

Thermal Characteristics (@T_A= +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	PD	1.5	W	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{θJA}	96	°C/W
Total Power Dissipation (Note 6)		PD	2.0	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R _{θJA}	72	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Electrical Characteristics (@TA= +25°C, unless otherwise specified.)

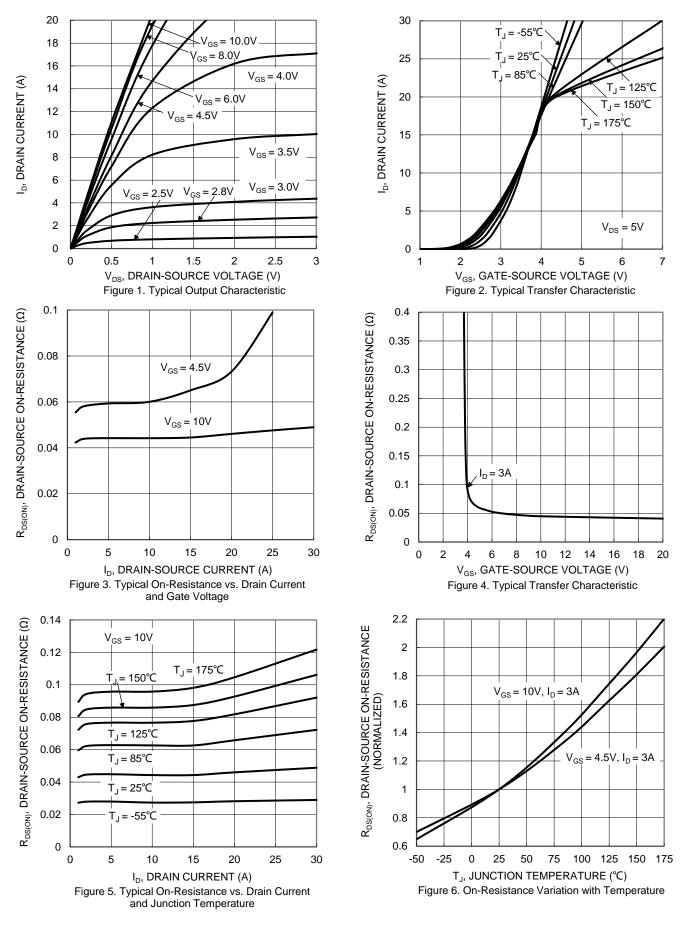
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						•
Drain-Source Breakdown Voltage	BVDSS	60	_		V	$I_D = 250 \mu A, V_{GS} = 0 V$
Zero Gate Voltage Drain Current	IDSS	_	_	1	μA	$V_{DS} = 60V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)	•					·
Gate Threshold Voltage	VGS(TH)	1.0	_	3.0	V	$I_D = 250 \mu A$, $V_{DS} = V_{GS}$
Static Drain-Source On-Resistance	Deserve		45	65		$V_{GS} = 10V, I_D = 3A$
Static Drain-Source On-Resistance	RDS(ON)	_	60	88	mΩ	$V_{GS} = 4.5V, I_{D} = 3A$
Diode Forward Voltage	V _{SD}	_	0.9	1.3	V	VGS = 10V, ID = 3A
DYNAMIC CHARACTERISTICS (Note 8)	•					·
Input Capacitance	Ciss	_	446			V _{DS} = 30V, V _{GS} = 0V f = 1MHz
Output Capacitance	Coss		113		pF	
Reverse Transfer Capacitance	Crss	_	10			
Gate Resistance	Rg		2.8		Ω	$V_{GS} = 0V, V_{DS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = 4.5V)	Qg		5.6			
Total Gate Charge (V _{GS} = 10V)	Qg	_	11.3		nC	
Gate-Source Charge	Qgs	_	1.5		nc	$V_{DS} = 30V, I_D = 3A$
Gate-Drain Charge	Qgd	_	2.4			
Turn-On Delay Time	t _{D(ON)}	_	8.8			
Turn-On Rise Time	tR	_	33.5	_		$V_{DD} = 30V, V_{GS} = 10V$
Turn-Off Delay Time	tD(OFF)	_	22.4		ns	$R_G = 4.7\Omega$, $I_D = 3A$
Turn-Off Fall Time	tF		19.4		1	
Body Diode Reverse Recovery Time	trr	_	31		ns	Is = 3A, dl/dt = 100A/µs
Body Diode Reverse Recovery Charge	Q _{RR}	_	23		nC	I _S = 3A, dl/dt = 100A/µs

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 Short duration pulse test used to minimize self-heating effect. Notes:

8. Guaranteed by design. Not subject to product testing.



DMNH6065SSD





f = 1MHz

 $\mathbf{C}_{\mathrm{iss}}$

 $\mathbf{C}_{\mathrm{oss}}$

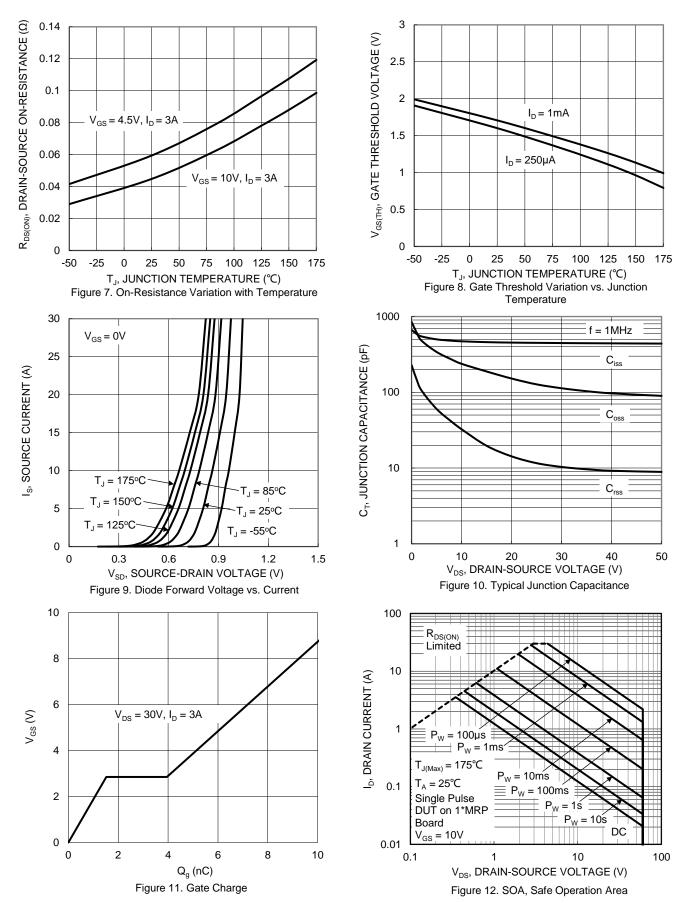
C_{rss}

40

= 10ś

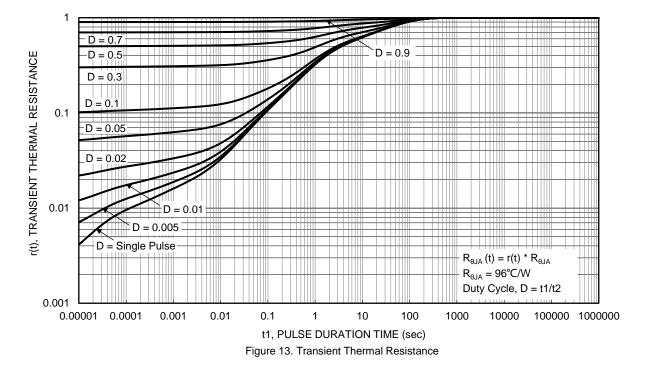
DC

50



100

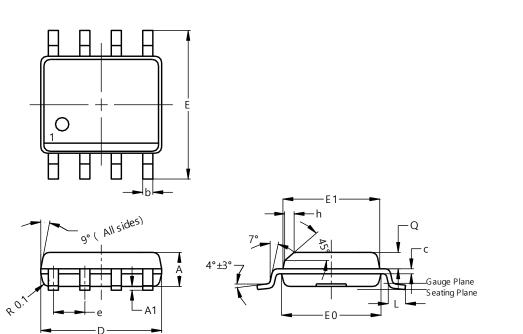






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

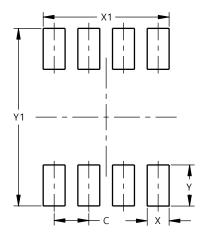


SO-8					
Dim	Min	Max	Тур		
Α	1.40	1.50	1.45		
A1	0.10	0.20	0.15		
b	0.30	0.50	0.40		
C	0.15	0.25	0.20		
D	4.85	4.95	4.90		
Е	5.90	6.10	6.00		
E1	3.80	3.90	3.85		
E0	3.85	3.95	3.90		
е			1.27		
h			0.35		
L	0.62	0.82	0.72		
Q	0.60	0.70	0.65		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8



Dimensions	Value (in mm)			
С	1.27			
Х	0.802			
X1	4.612			
Y	1.505			
Y1	6.50			



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